TOSHIBA Intelligent Power Module Silicon N Channel IGBT

MIG75Q202H

High Power Switching Applications Motor Control Applications

- Integrates inverter, brake power circuits & control circuits (IGBT drive units, protection units
 for over-current, realtime-current-control (RTC), under-voltage & over-temperature) in one
 package.
- The electrodes are isolated from case.

• High speed type IGBT : $V_{CE (sat)} = 3.5 \text{ V (Max)}$

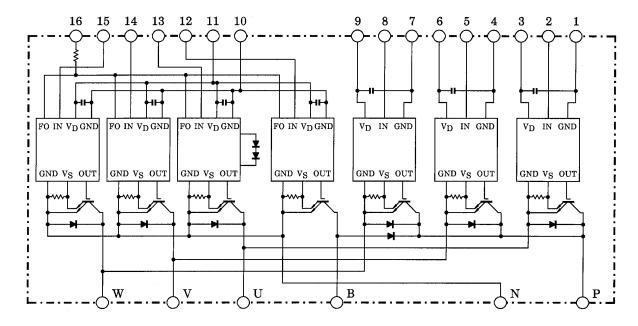
 $t_{off} = 2.8 \,\mu s \,(Max)$

 $t_{rr} = 0.21 \mu s (Max)$

Package dimensions: TOSHIBA 2-110A1A

• Weight: 520g

Equivalent Circuit



Maximum Ratings ($T_j = 25$ °C)

Stage	Characteristic	Condition	Symbol	Ratings	Unit
	Supply voltage	P-N power terminal	V _{CC}	900	V
	Collector-emitter voltage	_	V _{CES}	1200	V
Inverter	Collector current	Tc = 25°C, DC	Ic	75	Α
ilivertei	Forward current	Tc = 25°C, DC	I _F	75	Α
	Collector power dissipation	Tc = 25°C	PC	400	W
	Junction temperature	_	Tj	150	°C
	Supply voltage	P-N power terminal	V _{CC}	900	V
	Collector-emitter voltage	_	V _{CES}	1200	V
	Collector current	Tc = 25°C, DC	Ic	25	Α
Brake	Reverse voltage	_	V _R	1200	V
	Forward current	Tc = 25°C, DC	IF	25	Α
	Collector power dissipation	Tc = 25°C	PC	140	W
	Junction temperature	_	Tj	150	°C
	Control supply voltage	V _D -GND terminal	V _D	20	V
Control	Input voltage	IN-GND terminal	V _{IN}	20	V
Control	Fault output voltage	FO-GND (L) terminal	V _{FO}	20	V
	Fault output current	FO sink current	I _{FO}	10	mA
	Operating temperature	_	TC	-20 ~ +100	°C
Module	Storage temperature range	_	T _{stg}	-40 ~ +125	°C
iviodule	Isolation voltage	AC 1 minute	V _{ISO}	2500	V
	Screw torque	M5	_	3	Nm

Electrical Characteristics

a. Inverter Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	1	V _{CF} = 1200V	T _j = 25°C	_	_	1	mA
Collector cut-on current	ICEX	ACF - 1500A	T _j = 125°C	_	_	10	
Collector-emitter saturation	V _{CE} (sat)	V_D = 15 V, I_C = 75 A V_{IN} = 15 V \rightarrow 0 V	T _j = 25°C	_	2.6	3.5	V
voltage			T _j = 125°C	_	2.5	_	
Forward voltage	V _F	I _F = 75A		_	2.2	3.0	V
	t _{on}	V_{CC} = 600 V, I_C = 75 A V_D = 15 V, V_{IN} = 15 V \leftrightarrow 0 V Inductive load (Note 1)		_	1.0	1.7	μs
	t _{c (on)}			_	0.4	0.8	
Switching time	t _{rr}			_	0.16	0.21	
	t _{off}			_	1.9	2.6	
	t _{c (off)}			_	0.35	0.6	

b. Brake Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	ICEX	V _{CE} = 1200V	T _j = 25°C	-	_	1	- mA
Collector cut-on current			T _j = 125°C	1	_	10	
Collector-emitter saturation		V _D = 15 V,	T _j = 25°C	_	2.6	3.5	· V
voltage		$I_C = 25 \text{ A}$ $V_{IN} = 15 \text{ V} \rightarrow 0 \text{ V}$	T _j = 125°C	_	2.5	_	
Reverse current	I _R V _R = 12	V _R = 1200 V	- 4000 V		_	1	A
Reverse current	ir.	VR - 1200 V		_	_	10	mA
Forward voltage	V _F	I _F = 25A		_	1.4	2.2	V
	t _{on}	V_{CC} = 600 V, I_C = 25 A V_D = 15 V, V_{IN} = 15 V \leftrightarrow 0 V Inductive load		_	1.3	1.9	μs
	t _{c (on)}				0.85	1.6	
Switching time	t _{rr}			-	0.42	0.50	
	t _{off}		(Note 1)	_	1.9	2.6	
	t _{c (off)}				0.3	0.6	

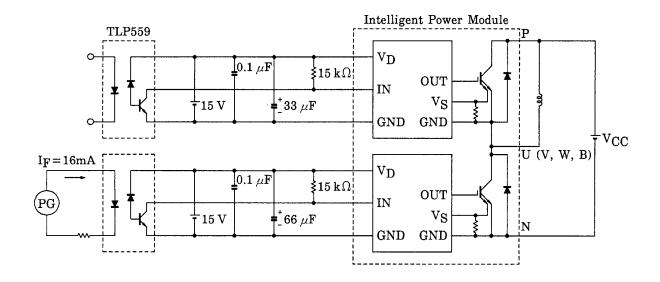
c. Control Stage $(T_j = 25^{\circ}C)$

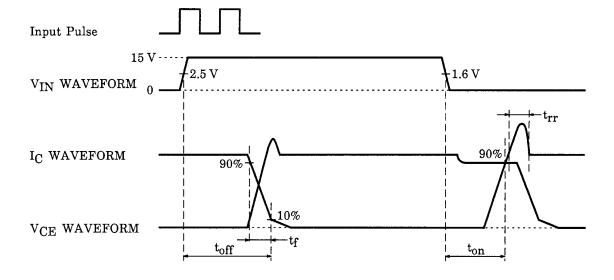
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Control circuit current	High side	I _{D (H)}	V _D = 15 V	_	8	12	mA
	Low side	I _{D (L)}	VD - 15 V	_	32	48	
Input-on signal voltage		V _{IN (on)}	V _D = 15 V, I _C = 75 mA	1.4	1.6	1.8	V
Input-off signal voltage		V _{IN} (off)	_	2.2	2.5	2.8	
Fault output current	Protection	I _{FO (on)}	- V _D = 15 V	5.4	6.0	6.6	mA
	Normal	I _{FO (off)}		_	_	0.1	
Over current protection trip level	Inverter	ОС	V _D = 15 V, T _j = 125°C	105	150	_	А
	Brake			40	50	_	
Short circuit protection trip level	Inverter		V _D = 15 V, T _j = 125°C	150	250	_	А
	Brake	sc		60	75	_	
Over current cut-off time		t _{off (OC)}	V _D = 15 V	_	5	_	μs
Over temperature protection	Trip level	OT	Case temperature	110	118	125	°C
	Reset level	OTr		_	98	_	
Control supply under voltage protection	Trip level	UV		11.0	12.0	12.5	.,
	Reset level	UVr	_	12.0	12.5	13.0	V
Fault output pulse width		t _{FO}	V _D = 15 V	1	2	3	ms

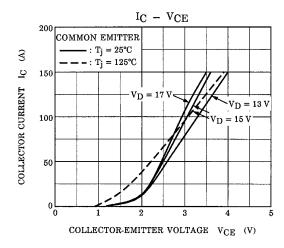
d. Thermal Resistance (T_j = 25°C)

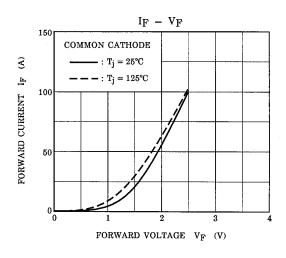
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
		Inverter IGBT stage	_	_	0.312	· °C/W
Junction to case thermal	R _{th (j-c)}	Inverter FRD stage	-	-	1.00	
resistance		Brake IGBT stage	_	_	0.892	
		Brake FRD stage	_	_	2.00	
Case to fin thermal resistance	R _{th (c-f)}	Compound is applied	١	0.05	ı	°C/W

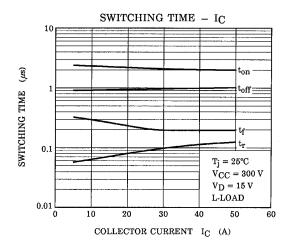
Note 1: Switching time test circuit & timing chart

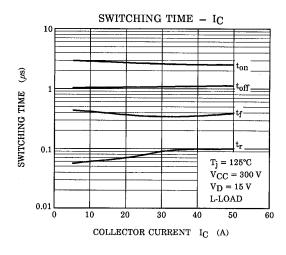


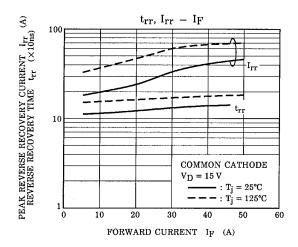


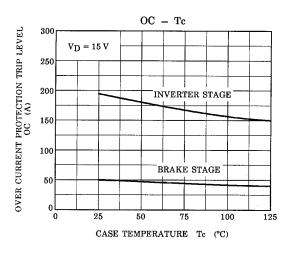


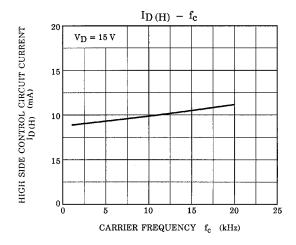


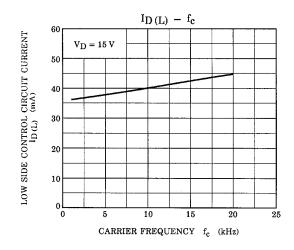


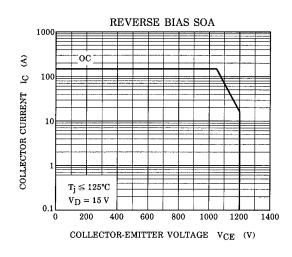


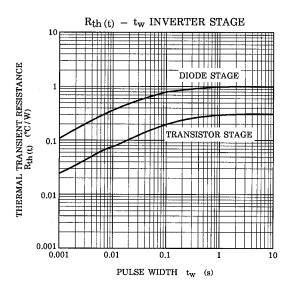


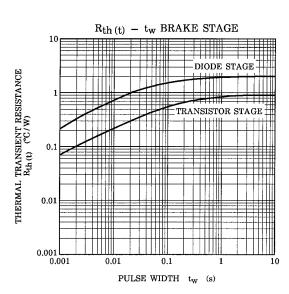






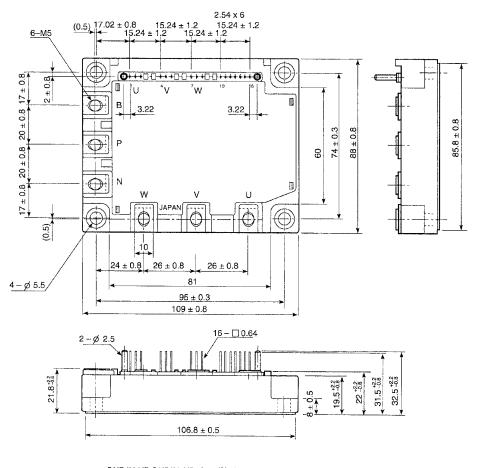






Package Dimensions: TOSHIBA 2-110A1A

Unit: mm



GNDIN VDGNDIN VDGNDIN VDGNDVD IN IN IN IN FO (U) (V) (W) (B) (X) (Y) (Z) , 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 Signal Terminal

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